## Summary of the context and overall objectives of the project

HiLight Semi-Conductor Limited is pioneering the use of CMOS to produce a world's first, very low power 100Gbps Chipset for data centres.

The current state of the art for data transmission within the data centre is inefficient. Optical Transceiver Modules (OTM), at 40Gbps and above, use power-hungry SiGe/BiCMOS technology in their Integrated Circuits. With a typical, large data centre containing at least 800,000 OTMs, they are responsible for around 8% of total energy use.

Demand for energy efficient technology for data centres is of great importance, commercially, environmentally and politically. Investment in European data centres is growing. By 2020, Europe's data centres will be using 104 Billion kWh energy every year. The EC's Code of Conduct for Energy Efficiency in Data Centres is designed to help stem this unsustainable situation, without hampering the critical function of data centres. In the near future, data centre energy costs may exceed the cost of their IT. Displacing the use of BiCMOS with CMOS, reduces power consumption and waste heat from data centre technical equipment (simultaneously avoiding cooling).

HiLight Semi-Conductor Limited has developed a disruptive CMOS Chipset that will unlock higher data rates, whilst reducing energy consumption significantly. This low-cost CMOS solution will also help reduce operating costs and enable data centres worldwide to cut energy use, contributing to global climate change targets.

## Work performed from the beginning of the project to the end of the period covered by the report and main results achieved so far (For the final period please include an overview of the results and their exploitation and dissemination)

The overall objective of this project is to successfully undertake vital prototyping, validation and demonstration activities to bring MERCURY to market-readiness. Due to the disruptive nature of MERCURY, it is anticipated that a 30% share in the global data centre market can be achieved by 2022, extending Europe's leadership as a Centre of Excellence in high speed Analog CMOS design.

## Progress beyond the state of the art, expected results until the end of the project and potential impacts (including the socio-economic impact and the wider societal implications of the project so far)

Internet data centres are consuming about 3% of the global electricity supply and account for about 2% of total greenhouse gas emissions. Data centres have a similar carbon footprint as the airline industry. It is expected that by 2020 greenhouse gas emissions from data centres will have quadrupled from 2007 levels, because of the increased data usage.

There are several limitations associated with the current state of the art used in this market, which are listed below:

- Uses expensive and lower yield BiCMOS technology
- BiCMOS is a relatively power-hungry technology, requiring typically 2.5 or 3.3 volts compared to approximately 1 volt in CMOS.
- Separate CDRs make the PCB profile too large for customer modules, without populating both sides of the board with components, which adds 50% to PCB production costs.
- Lack of integration increases cost and increases the complexity of wire bonding, further reducing yield.

HiLight Semi-Conductor Ltd is pioneering the use of CMOS to produce a world's first, very low power 100Gbps Chipset for data centres through this H2020 project "MERCURY".

Our innovation competes with BiCMOS, achieving high speeds, yet with cost and power savings. Displacing the use of BiCMOS with CMOS, will reduce power consumption and waste heat from data centre technical equipment (simultaneously reducing the need for cooling).

MERCURY is a highly innovative project. HiLight will be the first to use this new CMOS process in the OTM market.

Based on expected energy demand in European data centres, achieving our predicted global market penetration rates will lead to a total energy saving of 1.5 Billion kWh every year in European data centres (6 Billion kWh/year globally), by 2022, because of MERCURY's ultra-low power CMOS technology